

Reflective SP4T GaN High Power PIN Diode Switch Operating from DC to 6 GHz Up to 40 Watts (+46 dBm), < 100ns and SMA



PIN Diode Switches Technical Data Sheet

PE71S1104

Features

- · Reflective SPDT High Power PIN Diode Switch
- GaN Semiconductor Technology
- · Reflective Design
- Frequency Range: 500 MHz to 18 GHz
- Insertion Loss: 1.7 dB typ
- Isolation: 40 dB typ
- VSWR: 1.35:1 typ
- Maximum RF Input Power: +46 dBm

- Input IP3: +50 dBm typ
- Switching Speed: < 100 nsec
- TTL Compatible Driver Circuitry
- 50 Ohm Design
- SMA Female Connectors
- Compact Package Design withstands up to 95% Relative Humidity
- -45°C to +85°C Operating Temperature

Applications

- Aerospace & Defense
- Microwvae Radio
- Military & Commercial
- Communication
- VSAT
- SATCOM

- Test & Measuurement
- · Wireless Infrastructure
- Fiber Optics

Description

The PE71S1104 is a high power Reflective SP4T PIN Diode Switch that operates from DC to 6 GHz. The module utilizes Gallium Nitride (GaN) and chip-and-wire technology in the manufacturing process that ensures state-of-the-art power performance with excellent power-to-volume ratio that's ideal for broadband high power applications. The 50 ohm reflective design has impressive RF input power handling capability for cold switching up to +46 dBm, and incorporates TTL compatible driver circuitry for accurate logic control. Typical performance includes 1.7 dB insertion loss, 40 dB isolation, 1.35:1 VSWR, and < 100 nsec switching speed. Operational temperature range is -45°C to +85°C and the bias voltage requirement is +12 Vdc. The rugged and compact package supports SMA female connectors and is designed to meet a series of environmental conditions including Altitude, Vibration, Humidity, and Shock. Model PE71S1109 is the same switch design but includes an integrated heatsink.

Electrical Specifications

TTL Control Off/Isolation: 0 to 0.8 V On/Low Loss: 2.8 to 5 V

Description	Minimum	Typical	Maximum	Units
Frequency Range	DC		6	GHz
Impedance		50		Ohms
VSWR		1.35:1	1.5:1	
Insertion Loss		1.5	2	dB
IL Temperature Coefficient		0.003		dB/degC
Isolation	25	40		dB
Switching Time			100	ns
0.1dB Compression Point		+50		dBm
Input IP3		50		dBm
RF Input Power (CW)*			40	Watts
DC Power Dissipation		1		Watt

Click the following link (or enter part number in "SEARCH" on website) to obtain additional part information including price, inventory and certifications: Reflective SP4T GaN High Power PIN Diode Switch Operating from DC to 6 GHz Up to 40 Watts (+46 dBm), < 100ns and SMA PE71S1104

Pasternack Enterprises, Inc. • P.O. Box 16759, Irvine, CA 92623 **Phone:** (866) 727-8376 or (949) 261-1920 • **Fax:** (949) 261-7451

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Positive Operating Voltage		12		Vdc
Current @ 12 Vdc		200		mA
Operating Temperature	-45		+85	deg C

Performance by Frequency

Description	F1	F2	F3	F4	F5	Units
Frequency Range	DC to 3	3 to 6				GHz
VSWR, Max	1.3:1	1.5:1				
VSWR, Typ	1.2:1	1.35:1				
Insertion Loss, Max	1.5	2				dB
Insertion Loss, Typ	1	1.7				dB
Isolation, Min	35	25				dB
Isolation, Typ	42	30				dB

Electrical Specification Notes:

Internal TTL Driver will become damaged if Negative Voltage is applied

Absolute Maximum Rating

Parameter	Rating		
Biasing	+12V±10%		
TTL Control Voltage	0~0.8V/2.8~5V		



ESD Sensitive Material, Transport material in Approved ESD bags. Handle only in approved ESD Workstation.

Mechanical Specifications

Size

Length 1.97 in [50.04 mm] 1.97 in [50.04 mm] Width 0.37 in [9.4 mm] Height Weight 0.3 lbs [136.08 g] Design Reflective, SP4T RF Connector **SMA Female**

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^{*}Cold Switching: Before changing any TTL signal(s), the RF input power must be blanked or the switch could become



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100% RH @ 35°C, 95% RH @ 40°C

20G for 11ms Half Sinewave, 3 axis both directions

30,000 ft. (Epoxy Sealed Controlled Environment)

25g RMS (15° 2KHz) endurance, 1 hr per axis

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Environmental Specifications

Temperature

Operating Range -45 to +85 deg C Storage Range -55 to +125 deg C

Humidity Shock

Vibration Altitude

Compliance Certifications (see product page for current document)

Plotted and Other Data

Notes:

Typical Performance Data



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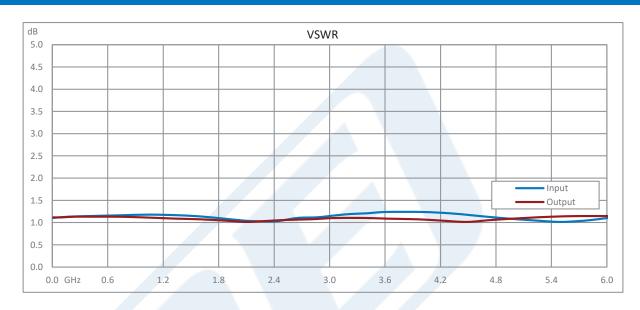






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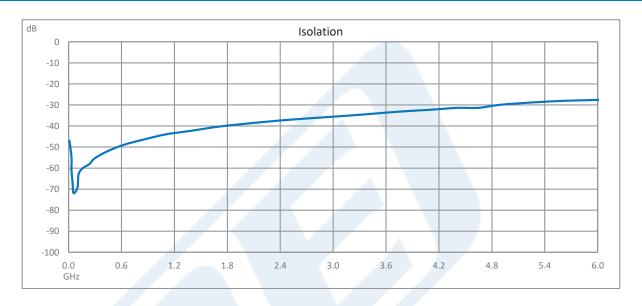


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URL: https://www.pasternack.com/sp4t-pin-diode-switch-6-ghz-40-watts-sma-pe71s1104-p.aspx

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PE71S1104 CAD Drawing

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